

Power spectrum of fermionic heat current fluctuations

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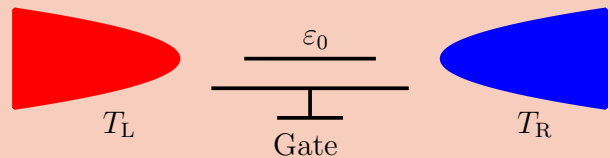
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We analyze the fluctuations of an electronic heat current across an idealized molecular junction. Apart from an induced, finite inter-electrode heat current the focus will be on the spectral features of the resulting heat current fluctuations. By use of the Green function method we derive an explicit expression for the power spectral density of the emerging heat current fluctuations. The complex expression simplifies considerably in the limit of zero frequency, yielding the noise intensity of the heat current. This spectral density for the heat fluctuations still depends on the frequency in the zero-temperature limit, assuming different asymptotic behaviors in the low- and high-frequency regions. We further address some subtleties and open problems from an experimental viewpoint.



(color online) Sketch of a molecular junction which transfers thermal energy carried by electrons from a hot electrode T_L across an idealized molecular junction towards a neighboring cold one T_R . Here, the inter-electrode electronic level ε_0 can be controlled continuously.

1 Introduction The experimental activities over the last fifteen years in investigating transport across molecular junctions [1, 2] has triggered a wave of intense research in both communities, theoretically [3, 4, 5, 6] and as well as in experiment [7, 8, 9, 10]. Single molecule electronics is still considered as a possible candidate for the substitution of the silicon-based elements in the information processing technology [7, 8]. This fact makes studies of molecular transport properties very appealing. Likewise, such molecular junctions seemingly have advantages in the context of energy-related applications. This is due to their potential for hybrid solid-state molecular structure which yields novel interface properties and the abundant selection of

possible molecules and electrode materials which allow to tailor specific properties on demand. In particular the issue of thermoelectric conversion and photovoltaic conversion processes continues to attract interest in pursuing research in molecular electronics.

Apart from the current-voltage characteristics [1, 9, 10], it is also possible, for example by use of full counting statistics [11, 12, 13, 14], to extract information about the fluctuations of the electric current flowing through a molecular wire [15, 16, 17, 18, 19]. In this context, the issue of heat or phonon transport across such molecular junctions plays a non-negligible role which may well crucially impact the electronic transport features, including the over-

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all stability issue of the molecular junction setup. It must also be realized that the experimental exploration of heat transport presents not at all a straightforward task. With this work we shall mainly explore the fluctuations of heat current caused by the transferring electrons.

With the systems of interest operating on the nanoscale the corresponding heat current fluctuations can become sizable. This may be so even in situations where the average heat current is *vanishing* identically, as it is the case in thermal equilibrium with both interconnecting electrodes held at the same temperature. Moreover, the properties of noise correlation features, or likewise, its frequency-dependent spectral properties and, as well, its zero-frequency power spectrum, are in no obvious manner related to the mean value of the heat flow itself. Our goal is to obtain analytical estimates for its *power spectral density* (PSD), even at the expense that these may mainly apply to idealized setups only. With such a restriction these analytical results may nevertheless be useful to appraise the role of heat current noise in more realistic molecular junctions. It is further of interest to have an estimate available when devising molecular circuitry for more complex tasks.

Heat transport across a molecular structure which links two electrodes is induced by a difference of the corresponding lead temperatures, i.e. T_L at the left-sided electrode and T_R at the right-sided electrode. The physics of heat transfer generally involves both electrons and phonons and their mutual interaction [6, 20, 21, 22, 23, 24, 25, 26, 27, 28, 29]. Therefore, the intensity of heat flow carried across the wire should be addressed with care, with the need to distinguish between heat transfer mediated either by electrons or phonons, or a combination of both. If phonons are mainly at work this topic relates to the new field of *phononics* [30], a novel research area which may lead to new circuit elements, such as molecular thermal diodes, thermal transistors, thermal logic gates, to name but a few [30, 31, 32, 33, 34, 35, 36]. Here also, the size of fluctuations in heat current does matter; this is so because those may well turn out to be deleterious to intended information processing tasks.

Energy transport mediated by electrons which relates at the same time to charge transfer: electrons are moving from lead to lead, carrying not only charge but also energy. However, the amount of energy transferred by a single electron, unlike to its charge, is not quantized [37, 38]. In contrast to the studies that examine the average heat flow much less attention, however, has been paid to the issue and impact of *fluctuations* of the accompanying heat flow. In a prior work [39] the heat transport through a ballistic quantum wire has been considered in the Luttinger-liquid limit, by neglecting the discreteness of the wire's energy spectrum. Likewise, with Refs. [40, 41], the PSD of the heat current fluctuations has been derived within the scattering theory, under the assumption that the electrons are transmitted (reflected) at the same rates, independently of their actual energies. The results of the last two papers, how-

ever, are distinctive because they have shown that the noise characteristics of heat current exhibits a well-pronounced frequency dependence even in the zero-temperature limit.

2 Molecular junction setup

Here we shall consider the *electronic* heat current that proceeds across a molecular wire composed of a single energy level with the two leads held at constant temperatures. A preliminary short report of electronic heat noise features has been presented by us with Ref. [42]. Here we extend this study and present further details on the theoretical derivation of the noise expression and discuss the features of the noise of the emerging heat current over much broader parameter regimes and frequency regimes away from the zero-frequency result. In order to obtain analytical tractable expressions we shall neglect electron-phonon interactions and, as well, electron-electron interactions. Such a simplification can be justified for tailored situations that involve a very short wire only. Then, the Coulomb interaction via a double occupancy shifts the energy far above the Fermi level so that its role in thermal transport can be neglected. Likewise, the electron dwell time is short as compared to the electron-phonon relaxation time scale. Note however, that in contrast to previous works [40, 41] we account here for the dependence of the transmission coefficient on its electron energies, and, within the Green function approach [5, 29], derive an explicit expression for the PSD of the heat current fluctuations, $\tilde{S}^h(\omega)$. In particular we show below that the net noise features of the heat current are quite distinct from their electronic counterpart.

Our model molecular junction setup is depicted with Fig. 1: It is described by a Hamiltonian

$$H = H_{\text{wire}} + H_{\text{leads}} + H_{\text{contacts}} . \quad (1)$$

It contains three different contributions, namely the wire Hamiltonian, the leads and the wire-lead coupling, respectively. We consider here the regime of *coherent* quantum

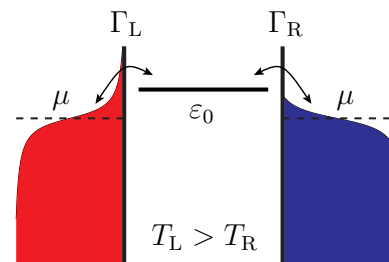


Figure 1 (color online) Idealized setup of a molecular junction used in text: Two metal leads, filled with electron gas, are connected by a single orbital ε_0 . The coupling strengths are determined by the constants $\Gamma_{L/R}$. The left lead is prepared at a higher temperature as compared to the opposite right lead, i.e. $T_L > T_R$. The chemical potential, μ , is the same for both leads so that no electric current due to a voltage bias is present.

transport whereby neglecting dissipation inside the wire. The wire is composed of a single orbital; i.e.,

$$H_{\text{wire}} = \varepsilon_0 d^\dagger d, \quad (2)$$

at an energy ε_0 , with the fermionic creation and annihilation operators, $d^\dagger$ and d . The energy level ε_0 can be tuned by applying a gate voltage. This so set up idealized model allows for explicit analytical calculations. Physically, it mimics a double barrier resonant tunneling structure GaAs/Al_xGa_{1-x}-structure of the type considered for electronic shot noise calculations in Ref. [43], herein truncated to a single Landau level. As commonly done, the electrodes are modeled by reservoirs, composed of ideal electron gases, i.e.,

$$H_{\text{leads}} = \sum_{\ell q} \varepsilon_{\ell q} c_{\ell q}^\dagger c_{\ell q}, \quad (3)$$

where the operator $c_{\ell q}^\dagger (c_{\ell q})$ creates (annihilates) an electron with momentum q in the $\ell = \text{L}$ (left) or $\ell = \text{R}$ (right) lead. We assume that the electron distributions in the leads are described by the grand canonical ensembles at the temperatures $T_{\text{L/R}}$ and with chemical potentials $\mu_{\text{L/R}}$. With such ideal electron reservoirs we then obtain

$$\langle c_{\ell q}^\dagger c_{\ell' q'} \rangle = \delta_{\ell \ell'} \delta_{q q'} f_\ell(\varepsilon_{\ell q}), \quad (4)$$

where

$$f_\ell(\varepsilon_{\ell q}) = \left[e^{(\varepsilon_{\ell q} - \mu_\ell)/k_B T_\ell} + 1 \right]^{-1} \quad (5)$$

denotes the Fermi function.

We impose a finite temperature difference $\Delta T = T_{\text{L}} - T_{\text{R}}$ and use identical chemical potentials, $\mu_{\text{L}} = \mu_{\text{R}} = \mu$ for the electrodes. When an electron tunnels out from a lead, the energy E is transferred into the wire which presents the heat transfer, δQ . Observing the value for the chemical potential, μ , it reads $\delta Q = E - \mu$. In the following we use that all the electron energies are measured from the chemical potential value μ , being set at $\mu = 0$.

The Hamiltonian which describes the tunneling events reads:

$$H_{\text{contacts}} = \sum_{\ell q} V_{\ell q} c_{\ell q}^\dagger d + h.c. \quad (6)$$

This part mediates the coupling between the wire and the electrodes. Here, the notation *h.c.* denotes Hermitian conjugate. The quantity $V_{\ell q}$ is the tunnelling matrix element, and the tunneling coupling is characterized in general by a spectral density,

$$\Gamma_\ell(E) = 2\pi \sum_q |V_{\ell q}|^2 \delta(E - \varepsilon_{\ell q}). \quad (7)$$

In the following, we shall use a wide-band limit of the electrode conduction bands, setting $\Gamma_\ell(E) := \Gamma_\ell$.

3 Power spectral density of electronic heat current fluctuations

Working within the Heisenberg description of operators we present the derivation of the electronic heat current and the PSD of its corresponding fluctuations. The heat current is given by

$$J_{\text{L}}^{\text{h}}(t) = \frac{\sum \delta Q(t)}{\Delta t}. \quad (8)$$

With our choice of chemical potentials, we find that the heat transfer operator is $\delta Q(t) = E_{\text{L}}$, with the energy operator given by

$$E_{\text{L}} = \sum_q \varepsilon_{\text{L}q} c_{\text{L}q}^\dagger c_{\text{L}q}. \quad (9)$$

Its time derivative thus yields the operator for the heat current, reading:

$$J_{\text{L}}^{\text{h}}(t) = - \sum_q \frac{2\varepsilon_{\text{L}q}}{\hbar} \text{Im}[V_{\text{L}q} c_{\text{L}q}^\dagger(t) d(t)]. \quad (10)$$

The heat current is positive valued when heat transport proceeds from the hot left lead, i.e. $T_{\text{L}} > T_{\text{R}}$ to the adjacent cold lead, see in Fig. 1. Deriving the above expression, we have employed the Heisenberg representation for the lead electron operators. The average current is obtained by the ensemble average $\langle J_{\text{L}}^{\text{h}}(t) \rangle$. Because we consider only the heat transport by electrons, we have $\langle J_{\text{L}}^{\text{h}}(t) \rangle = -\langle J_{\text{R}}^{\text{h}}(t) \rangle$, due to the conservation of energy. We henceforth focus on the quantities derived with regard to the left lead.

The quantum correlation function of heat current fluctuations is described by the *symmetrized* autocorrelation function, i.e.,

$$S^{\text{h}}(t, t') = \frac{1}{2} \langle [\Delta J_{\text{L}}^{\text{h}}(t), \Delta J_{\text{L}}^{\text{h}}(t')]_+ \rangle, \quad (11)$$

with respect to the operator of the heat current fluctuation

$$\Delta J_{\text{L}}^{\text{h}}(t) = J_{\text{L}}^{\text{h}}(t) - \langle J_{\text{L}}^{\text{h}}(t) \rangle. \quad (12)$$

The heat current noise is described here with $\tau = t - t'$ by the *symmetrized* quantum autocorrelation function

$$S^{\text{h}}(\tau) = 1/2 \langle [\Delta J_{\text{L}}^{\text{h}}(\tau), \Delta J_{\text{L}}^{\text{h}}(0)]_+ \rangle, \quad (13)$$

of the heat current fluctuation operator $\Delta J_{\text{L}}^{\text{h}}(s) = J_{\text{L}}^{\text{h}}(s) - \langle J_{\text{L}}^{\text{h}}(s) \rangle$, where the anti-commutator $[A, B]_+ = AB + BA$ ensures the hermitian property.

With this work we throughout consider the asymptotic long time limit $t \rightarrow \infty$ when all transients are decayed. In this asymptotic limit the average heat current is stationary and the autocorrelation function of the heat current fluctuations becomes time-homogeneous; i.e. it is independent of initial preparation effects. It thus depends on the time difference $\tau = t - t'$ only. The Fourier transform yields the

power spectral density (PSD) $\tilde{S}^h(\omega)$ for the heat current noise, i.e.,

$$\tilde{S}^h(\omega) = \tilde{S}^h(-\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} S^h(\tau) \geq 0. \quad (14)$$

$\tilde{S}^h(\omega)$ is an even function in frequency and strictly semi-positive, in accordance with the Wiener-Khinchin theorem [44]. In the following we address positive values of the frequency, $\omega > 0$, only.

The annihilation operators of the electrode states satisfy the Heisenberg equations of motion; i.e.,

$$\dot{c}_{\ell q}(t) = -\frac{i}{\hbar} \varepsilon_{\ell q} c_{\ell q}(t) - \frac{i}{\hbar} V_{\ell q} d(t), \quad (15)$$

yielding the solution

$$c_{\ell q}(t) = c_{\ell q}(t_0) e^{-i\varepsilon_{\ell q}(t-t_0)/\hbar} - \frac{iV_{\ell q}}{\hbar} \int_{t_0}^t dt' e^{-i\varepsilon_{\ell q}(t-t')/\hbar} d(t'). \quad (16)$$

Here, the first term on the right hand side describes the dynamics of the free electrons in the leads, while the second term accounts for the influence of the molecule.

The Heisenberg equation of the molecular annihilation operator is given by

$$\dot{d}(t) = -\frac{i}{\hbar} \varepsilon_0 d(t) - \frac{i}{\hbar} \sum_{\ell q} V_{\ell q}^* c_{\ell q}(t). \quad (17)$$

Upon inserting Eq. (16) into Eq. (17), we obtain

$$\dot{d} = \frac{i}{\hbar} \varepsilon_0 d(t) - \frac{\Gamma_L + \Gamma_R}{2\hbar} d(t) + \xi_L(t) + \xi_R(t), \quad (18)$$

where we have defined the noise operator

$$\xi_{\ell}(t) = -\frac{i}{\hbar} \sum_q V_{\ell q}^* \exp\left[-\frac{i}{\hbar} \varepsilon_{\ell q}(t-t_0)\right] c_{\ell q}(t_0). \quad (19)$$

In addition, we have employed the definition (7) and used the wide-band limit.

The noise quantity defined in Eq. (19) denotes operator-valued Gaussian noise, which is characterized by its mean and correlation properties, reading

$$\langle \xi_{\ell}(t) \rangle = 0 \quad (20)$$

$$\langle \xi_{\ell'}^{\dagger}(t') \xi_{\ell}(t) \rangle = \delta_{\ell\ell'} \int_{-\infty}^{\infty} \frac{d\varepsilon}{2\pi\hbar^2} e^{-i\varepsilon(t-t')/\hbar} \Gamma_{\ell}(\varepsilon) f_{\ell}(\varepsilon). \quad (21)$$

This noise accounts for the influence of the states stemming from the electrodes $l = L, R$.

Now the central problem is to solve the inhomogeneous differential equation (18). Once we obtain the solution of

Eq. (18), we obtain also the solution for Eq. (16), the heat current (10) and also the power spectral density in Eq. (14).

To obtain the solution we follow the Green function approach in Ref. [5] and start with solving the following differential equation

$$\left(\frac{d}{dt} + \frac{i\varepsilon_0}{\hbar} + \frac{\Gamma_L + \Gamma_R}{2\hbar}\right) G(t-t') = \delta(t-t'), \quad (22)$$

followed by the application of the convolution $d(t) = \int G(t-t')(\xi_L(t') + \xi_R(t'))dt'$. The solution of Eq. (22) is thus given by:

$$G(t) = \theta(t) e^{-i\varepsilon_0 t/\hbar - (\Gamma_L + \Gamma_R)t/2\hbar}. \quad (23)$$

Then, the molecular operator in Eq. (18) assumes the form

$$d(t) = \sum_{\ell q} V_{\ell q}^* \frac{\exp[-i\varepsilon_{\ell q}(t-t_0)/\hbar]}{\varepsilon_{\ell q} - \varepsilon_0 + i(\Gamma_L + \Gamma_R)/2} c_{\ell q}(t_0). \quad (24)$$

In what follows we address solely the asymptotic properties which are reached with the initial time of preparation $t_0 \rightarrow -\infty$. This implies that average currents assume stationary values and correlation functions become time-homogeneous. With this expression and its Hermitian conjugate, we obtain the occupation value of the molecular energy level ε_0 as

$$\begin{aligned} \bar{n}_{\varepsilon_0} &= \langle d^{\dagger}(t) d(t) \rangle \\ &= \sum_{\ell\ell'q'q} \frac{V_{\ell q} \exp[i\varepsilon_{\ell q}(t-t_0)/\hbar]}{[\varepsilon_{\ell q} - \varepsilon_0 - i(\Gamma_L + \Gamma_R)/2]} \\ &\quad \times \frac{V_{\ell'q'}^* \exp[-i\varepsilon_{\ell'q'}(t-t_0)/\hbar]}{[\varepsilon_{\ell'q'} - \varepsilon_0 + i(\Gamma_L + \Gamma_R)/2]} \langle c_{\ell q}^{\dagger}(t_0) c_{\ell'q'}(t_0) \rangle \\ &= \sum_{\ell q} \frac{|V_{\ell q}|^2 f_{\ell}(\varepsilon_{\ell q})}{(\varepsilon_{\ell q} - \varepsilon_0)^2 + (\Gamma_L + \Gamma_R)^2/4}, \end{aligned} \quad (25)$$

where we have employed the ensemble average, Eq. (4). We find that this occupation is determined first by the Fermi function of the leads weighted by the tunneling matrix elements $V_{\ell q}$, the difference among the energy levels of the lead states and between lead states and the molecular energy level ε_0 . This occupation value is time-independent since there is no time-dependent external fields present.

Upon substituting the result in Eq. (24) into Eq. (16), we find for the operators in the electrodes

$$\begin{aligned} c_{\ell q}(t) &= c_{\ell q}(t_0) e^{-i\varepsilon_{\ell q}(t-t_0)/\hbar} \\ &\quad + \sum_{\ell'q'} \frac{V_{\ell q} V_{\ell'q'}^* e^{-i\varepsilon_{\ell'q'}(t-t_0)/\hbar}}{\varepsilon_{\ell'q'} - \varepsilon_0 + i(\Gamma_L + \Gamma_R)/2} c_{\ell'q'}(t_0) \\ &\quad \times B[\varepsilon_{\ell'q'} - \varepsilon_{\ell q}], \end{aligned} \quad (26)$$

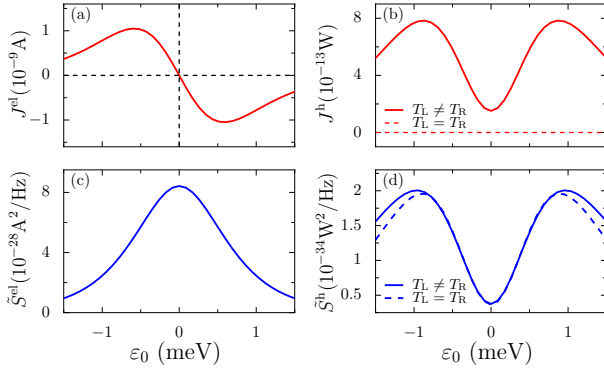


Figure 2 (color online) Average electronic currents (top row) for charge J^{el} and heat flow J^h and the zero-frequency values of corresponding PSDs of the accompanying current fluctuations (bottom row) for charge (left column) and heat (right column) transport through the single-orbital wire as functions of orbital energy for $\Gamma_R = \Gamma_L = \Gamma = 0.1$ meV. The remaining parameters are $T_L = 5.2$ K, $T_R = 3.2$ K (solid lines). For equal chemical potentials $\mu_L = \mu_R = 0$ the heat flow in panel (b) vanishes for equal temperatures $T_L = T_R$; its fluctuations in equilibrium at the temperature $T_L = T_R = 4.2$ K are depicted versus orbital energy ϵ_0 by the dashed line in panel (d). Figure adapted from Ref. [42].

where,

$$B(E) = \mathcal{P} \left(\frac{1}{E} \right) - i\pi\delta(E), \quad (27)$$

and $\mathcal{P}$ denotes the integral principal value. In going from Eq. (24) to Eq. (26) we have used Sokhotsky's formula which states that $\lim_{\epsilon \rightarrow 0} 1/(x + i\epsilon) = \mathcal{P}(1/x) - i\pi\delta(x)$, where $\mathcal{P}(1/x) = \int_{-\infty}^0 dx/x + \int_0^{\infty} dx/x$, see in Ref. [45].

Next we insert Eq. (24) and Eq. (26) into the heat current operator, Eq. (10), and by consequently taking the ensemble average, we obtain a Landauer-like formula for the heat current [6, 28, 48]; reading,

$$\langle J^h(t) \rangle := J^h = \frac{1}{2\pi\hbar} \int dE E \mathcal{T}(E) [f_L(E) - f_R(E)], \quad (28)$$

where the transmission coefficient

$$\mathcal{T}(E) = \Gamma_L \Gamma_R / [(E - \epsilon_0)^2 + \Gamma^2], \quad (29)$$

is energy-dependent.

The expression for the electric Seebeck current [6] reads very similar to Eq. (28), except for its absence of the energy multiplier E in the integral in the rhs of Eq. (28). This seemingly small difference changes, however, the physics of the transport through the wire, because the multiplier inverts the symmetry of the integral. Namely, the Seebeck current is an antisymmetric function of orbital energy and vanishes when the orbital energy level is aligned

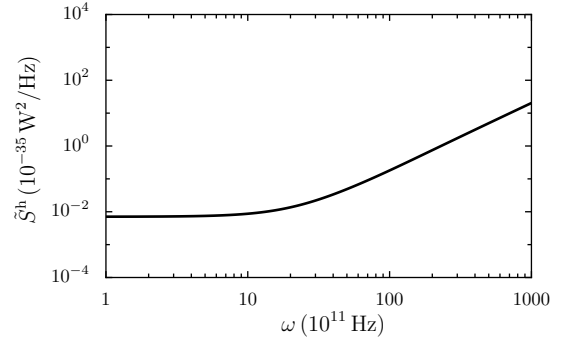


Figure 3 Power spectral density of the heat current noise as a function of the frequency ω at temperatures $T_L = 6$ K, $T_R = 2$ K. The other parameters are $\epsilon_0 = 0$ and $\Gamma = 0.1$ meV.

to the chemical potentials of the leads, Fig. 2(a), while the heat current is a symmetric function and acquires a nonzero value at $\epsilon_0 = 0$, Fig. 2(b).

3.1 Explicit results and discussion

Upon combining Eq. (14) and Eq. (10), we end up after a cumbersome evaluation with the nontrivial expression for the PSD of electronic heat current noise. Due to the complexity of this resulting expression the physics it inherits is not very illuminative. Nevertheless, we depict it here as given in our preliminary report [42], reading:

$$\begin{aligned} \tilde{S}^h(\Omega = \hbar\omega; T_L, T_R) &= \sum_{\pm} \int \frac{dE}{4\pi\hbar} \left\{ \left[\left(E \pm \frac{\Omega}{2} \right)^2 \mathcal{T}(E) \mathcal{T}(E \pm \Omega) \right. \right. \\ &\quad + \frac{\Gamma_L^2 [E(E - \epsilon_0) - (E \pm \Omega)(E \pm \Omega - \epsilon_0)]^2}{[(E - \epsilon_0)^2 + \Gamma^2][(E \pm \Omega - \epsilon_0)^2 + \Gamma^2]} \\ &\quad \times f_L(E) \bar{f}_L(E \pm \Omega) \\ &\quad + \left(E \pm \frac{\Omega}{2} \right)^2 \mathcal{T}(E) \mathcal{T}(E \pm \Omega) f_R(E) \bar{f}_R(E \pm \Omega) \\ &\quad + \left[\left(E \pm \frac{\Omega}{2} \right) \left(\pm \frac{\Omega}{2} \right) \frac{\Gamma_L^2 \mathcal{T}(E \pm \Omega)}{(E - \epsilon_0)^2 + \Gamma^2} \right. \\ &\quad + E^2 \mathcal{R}(E) \mathcal{T}(E \pm \Omega) \mp \frac{1}{2} E \Omega \mathcal{T}(E) \mathcal{T}(E \pm \Omega) \left. \right] \\ &\quad \times f_L(E) \bar{f}_R(E \pm \Omega) \\ &\quad + \left[(E \pm \Omega) \left(\pm \frac{\Omega}{2} \right) \mathcal{T}(E) \mathcal{T}(E \pm \Omega) \right. \\ &\quad + (E \pm \Omega)^2 \mathcal{R}(E \pm \Omega) \mathcal{T}(E) \\ &\quad + \left. \left(E \pm \frac{\Omega}{2} \right) \left(\mp \frac{\Omega}{2} \right) \frac{\Gamma_L^2 \mathcal{T}(E \pm \Omega)}{(E - \epsilon_0)^2 + \Gamma^2} \right] \\ &\quad \times f_R(E) \bar{f}_L(E \pm \Omega) \left. \right\}, \quad (30) \end{aligned}$$

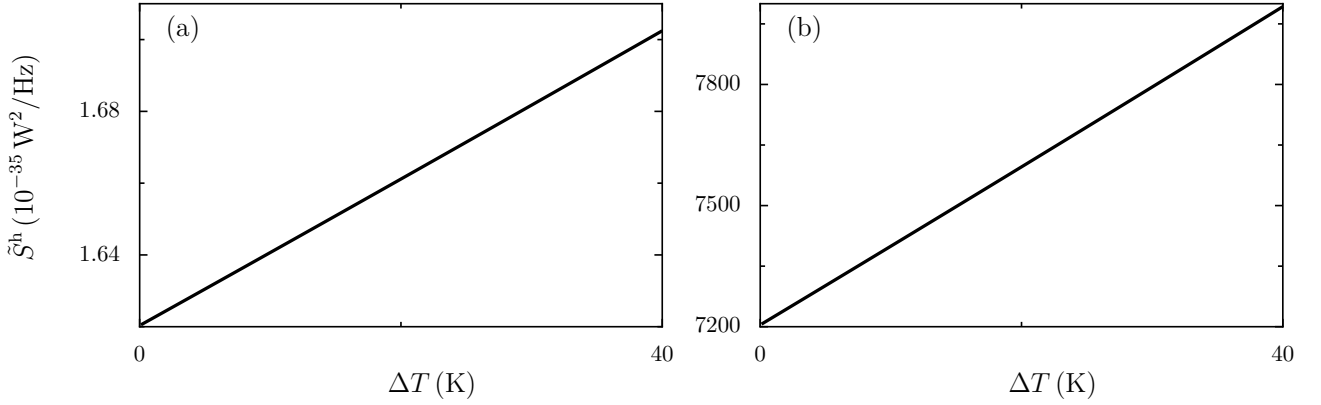


Figure 4 Power spectral density of heat current noise at frequency $\omega = 2.16 \times 10^{13} \text{ Hz}$ (which is the Debye cut-off frequency of gold) as a function of temperature difference with (a) weak molecule-wire coupling $\Gamma = 0.1 \text{ meV}$ or (b) strong molecule-wire coupling $\Gamma = 10 \text{ meV}$. The other employed parameters are $T_R = 300 \text{ K}$ and $\varepsilon_0 = 0$.

wherein we abbreviated $\Omega \equiv \hbar\omega$, $\bar{f} \equiv 1 - f$ with $\mathcal{R}(E) \equiv 1 - \mathcal{T}(E)$ denoting the reflection coefficient. Below we consider the case of symmetric coupling between the wire and the leads, $\Gamma_L = \Gamma_R = \Gamma$. It should also be mentioned that its explicit verification is experimentally not straightforward. Typically such a PSD can be measured only indirectly via a single-time measurement of a tailored linear response function via a corresponding, generally non-equilibrium quantum fluctuation-dissipation relation, which connects this response function with a corresponding quantum two-time correlation expression [44]. Put differently, this tailored response function is required to relate precisely to our quantum correlation of heat current fluctuations in (13). This is so because an explicit quantum measurement at two different times typically will impact (i.e. it will generally alter) the purely theoretically determined quantum correlation expression in Eq. (14), for further details see in Refs. [46, 47].

In Figure 3, we depict the dependence of the PSD of heat current noise versus frequency at the temperatures $T_L = 6 \text{ K}$, $T_R = 2 \text{ K}$. We find that the PSD depicts different power laws in different frequency regions and increases monotonically.

Moreover, we find that the spectral density strength Γ of the wire-lead coupling can change the dependence of the PSD of heat current noise on the parameters. In Figure 4 we depict the PSD of heat noise as a function of the temperature difference ΔT in the case of weak and strong wire-lead couplings. With weak coupling, the PSD is smaller by one order of magnitude and only slightly depends on ΔT . In contrast, it increases very fast with ΔT when the coupling is very strong. According to Eq. (29), the transmission coefficient becomes wider when Γ is larger, such that more electrons, whose energies deviate stronger from the chemical potential, are allowed to transport across the molecular junction. Therefore, the PSD becomes strongly enhanced and depends sensitively on

ΔT .

3.2 Zero frequency noise power

The PSD of heat current noise at zero frequency $\omega = 0$ simplifies considerably, assuming an appealing form

$$\begin{aligned} \tilde{S}^h(\omega = 0; T_L, T_R) &= \frac{1}{2\pi\hbar} \int dE E^2 [\mathcal{T}(E)[f_L(E)[1 - f_L(E)] \\ &\quad + f_R(E)[1 - f_R(E)] \\ &\quad + \mathcal{T}(E)[1 - \mathcal{T}(E)][f_L(E) - f_R(E)]^2] . \end{aligned} \quad (31)$$

Let us also contrast this result with the zero-frequency PSD of the fluctuations displayed by the nonlinear, accompanying Seebeck electric current. The latter reads [3, 5]:

$$\begin{aligned} \tilde{S}^{\text{el}}(\omega = 0; T_L, T_R) &= \frac{e^2}{2\pi\hbar} \int dE [\mathcal{T}(E)[f_L(E)[1 - f_L(E)] \\ &\quad + f_R(E)[1 - f_R(E)] \\ &\quad + \mathcal{T}(E)[1 - \mathcal{T}(E)][f_L(E) - f_R(E)]^2] , \end{aligned} \quad (32)$$

Most importantly, the zero-frequency PSD for heat current in Eq. (31) differs by the energy factor E^2 within the integrand. Although this distinction seemingly appears minor and may even be guessed beforehand without going through the laborious task of doing a theoretical rigorous derivation from which this limit derives from the final result in Eq. (30). It must be emphasized nevertheless that the two expressions lead to tangible differences. Particularly note the different behavior of the electronic and heat noise PSDs versus the tunable energy level ε_0 as depicted with Fig. 2 and in Fig. 5. While the zero-frequency component of the electric PSD at $\omega = 0$ exhibits a maximum at $\varepsilon_0 = 0$ its heat current PSD possesses instead a local minimum at

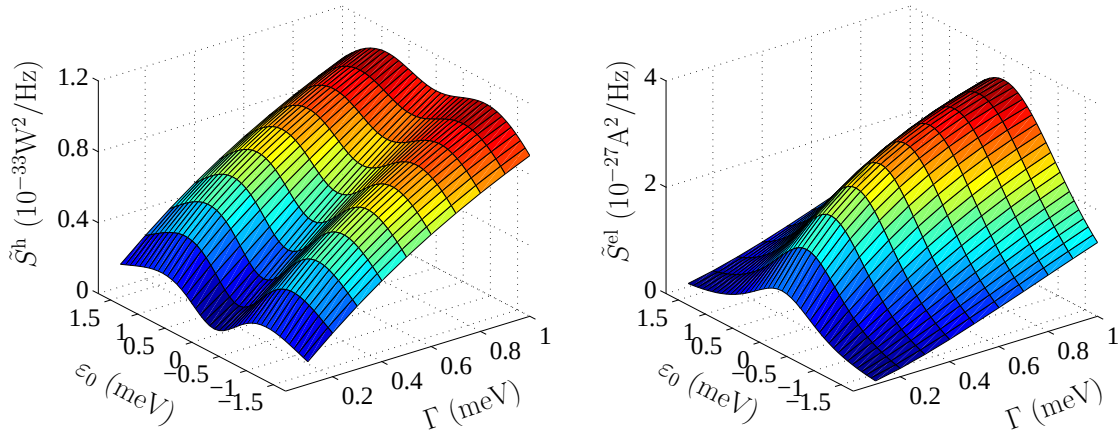


Figure 5 (color online) Power spectral density of the heat current noise at zero frequency $\omega = 0$, (left panel) and power spectral density of the electric current noise (right panel) as functions of the wire orbital site energy ε_0 and wire-lead coupling strength Γ . The parameters employed are $T_L = 6.2K$ and $T_R = 2.2K$.

this value. These two PSDs for charge current and heat current are compared in Fig. 5 over wide regimes of electronic orbital energy ε_0 and lead-molecule strength Γ .

These differences originate from the salient feature that the two transport mechanisms for charge and the energy are different. The electric current is quantized by the electron charge, e , while, in contrast, the energy carried by the electron is continuous and can assume principally an arbitrary value. Notably, the main contribution to the electronic noise power across the wire stems from those electrons occupying energy levels around the chemical potential $\mu = 0$. When ε_0 deviates from the chemical potential, increasingly less electrons participate in the transport. The flow of electron becomes diminished, and since both, the electric current and the electric noise are insensitive to the electron kinetic energies, they both decrease with increasing $|\varepsilon_0|$. This scenario differs for heat flow: There, the deviation from the chemical potential increases the possibility that successive electrons will carry different energies. This in turn causes an increase of heat current noise. With further deviation of the orbital energy from the chemical potential, the occupancy difference $[f_L(E) - f_R(E)]$ decreases monotonically; consequently the heat flow noise power decreases again.

3.3 Electronic heat current noise in thermal equilibrium

Finally, let us focus on the thermal equilibrium heat current noise properties which are attained when the two temperatures are set equal, i.e. if $T_L = T_R$. In this case the average heat current vanishes identically, while its fluctuations remain finite. The zero-frequency spectra of both noise spectra for heat and electric current noise increase upon increasing the coupling strength Γ . This is so because the transmission probability increases. The corre-

sponding noise intensities assume nonzero values in equilibrium, however, as depicted with Fig. 2, see in panel 2(d).

The properties at vanishing temperature, $T_L = T_R = 0$, are even more subtle. Here, the heat current PSD still depends on frequency. This dependence originates from quantum fluctuations where virtual transitions of electrons directly from lead-to-lead occur [40,41]. The Fermi distribution equals the Heaviside step function in this case. Therefore, the contributions to the integrand in Eq. 30 stems from the interval $[-\Omega, 0]$. After an integration of Eq. (30), one finds for the frequency dependent PSD the expression:

$$\begin{aligned} \tilde{S}^h(\omega, T_L = T_R = 0) &= \frac{\Gamma}{4\pi\hbar} \left\{ [(2\Omega)^2 - 2\Gamma^2] \arctan\left(\frac{\Omega}{\Gamma}\right) \right. \\ &\quad \left. + 2\Omega\Gamma \left[1 + \log\left(\frac{\Gamma^4}{(\Omega^2 + \Gamma^2)^2}\right) \right] \right\}, \quad \Omega = \hbar\omega. \end{aligned} \quad (33)$$

In the limit $\Gamma \rightarrow \infty$ the zero-temperature PSD thus scales like $\tilde{S}^h(\omega) \propto \omega^3$. This is in full agreement with the results obtained in Refs. [40,41], where this asymptotic behavior is found to be uniform throughout the whole frequency region. However, this is no longer so when Γ is finite: the second term in the rhs of Eq. (33) introduces a linear cutoff in the limit $\omega \rightarrow 0$, $\tilde{S}^h(\omega) \propto \omega$. In distinct contrast, in the high-frequency region, the first term in the rhs of Eq. (33) becomes dominating. As a consequence, the PSD (33) approaches a square-law asymptotic crossover dependence, $\tilde{S}^h(\omega) \propto \omega^2$, in the high-frequency limit.

4 Conclusions and open sundry topics

By using the Green function formalism we have investi-

gated electronic heat current. Our focus centered on the issue of the heat current fluctuations in a molecular junction model composed of a single orbital molecular wire. For the noninteracting case we succeeded in deriving a closed form for the frequency dependence of heat current noise; i.e. the heat noise PSD, both in nonequilibrium $T_L \neq T_R$ and in thermal equilibrium $T_L = T_R$. The dependence of the heat current noise on the orbital energy ε_0 is qualitatively different from that for the accompanying electric current noise, see Fig. 5. Moreover, the heat current fluctuation properties depend strongly on the overall tunneling coupling strength $\Gamma_L = \Gamma_R = \Gamma$.

In the zero-temperature limit, the PSD of the heat current noise obeys two distinctive asymptotic behaviors, being different in the low-frequency and the high-frequency regions. The particular square-law shape of the PSD in the high-frequency region is due to the Lorentzian shape of the transmission coefficient $\mathcal{T}(E)$ in Eq. (29). Yet, the general effect would remain for any choice of the coefficient in the form of a localized, bell-shaped function: the noise spectrum will deviate from a cubic power-law asymptotic behavior upon entering the high-frequency region.

As emphasized in our introduction, with this work only the electron subsystem has been considered. Realistic heat transport in real molecular junctions would involve the complexity of interacting electrons and electron-phonon interactions [6]. This electronic heat transport may dominate in certain situations so that the measured heat noise can be attributed approximately to the electronic component only. The unified approach, which would include both the electron and the phonon subsystems, as well as the effects of their interactions, presents a future challenge although several contributions in this direction for the average heat current (but not the heat current noise PSD) have already been undertaken before [6, 25, 28, 48].

4.1 Open issues

We conclude this study with further remarks that may shed light on pressing open problems and in addition may invigorate others to pursue future work along these lines. A first observation is that we obtained within the Green function analysis tractable expressions for quantum transport in the steady state without ever having to invoke the explicit knowledge of the inherent nonequilibrium density operator. Naturally, the quantum averages for the current and the auto-correlation of the quantum fluctuations carry less information as encompassed with the full steady state nonequilibrium density operator. The latter nonequilibrium density operator is typically very difficult to obtain and explicit results are known for tailored situations only. In fact, explicit results are very intricate already for those cases with overall quadratic Hamiltonians only [49].

A much more subtle issue refers to the experimental detection of quantum correlation features. In clear contrast to the case with a quantum, single-time expectation of a quantum observable the issue of measurement of manifest quan-

tum correlations is a delicate and difficult issue that is only rarely addressed with sufficient care in the literature. This is so because the mere calculation of a theoretical two-time quantum correlations does not say anything about its feasible experimental measurement scenario. Either strong, i.e. of the von Neumann-type, or weak quantum measurements impact the dynamics as clearly manifested with the example of with the Zeno-effect [50, 51]. With more that one time present this objective relates to the problem of measurements of quantities that are not quantum observables [46, 47, 52, 53]. To appreciate the complexity somewhat in more detail let us first consider the case with classical random variables. Then the PSD can be obtained experimentally as the limit of a time average of the *classical* random process $J_L^h(t)$, via considering the

$$S(\omega) = \lim_{T \rightarrow \infty} \frac{1}{2T} \left| \int_{-T}^T J_L^h(t) \exp(i\omega t) dt \right|^2. \quad (34)$$

Note that classically the measurement of the *random* variable of the momentary heat flow $J^h(t)$ at time t presents no serious conceptional problem while the same is not at all straightforward as a function of continuous time t for a quantum dynamics. Moreover, even classically, the result in Eq. (34) holds true only when the finite value $S_T(\omega)$ tends to the exact value $S(\omega)$ with its variance approaching zero as $T \rightarrow \infty$. The latter implies conditions of higher, fourth-order correlations to be satisfied [54]. With the non-commutation property of quantum observables at different times at work no such direct scenario is available for the experiment. Here the complexity of quantum measurements will enter in its full generality. In certain situations, however, the task simplifies fortunately.

Consider the case of quantum linear response theory. The measurement of a single observable (here the heat flux operator) due to an external perturbation is typically related to the evaluation of a specific quantum correlation function. The case of the quantum-dissipation relation of Callen-Welton presents such a celebrated case [55, 56, 57]. There, the dissipative part of the measurable, frequency-dependent susceptibility of a perturbed observable B is uniquely related to the PSD $S_{BA}(\omega)$ of quantum fluctuations of the observable B and the fluctuations of observable A to which the applied external force couples. In our case it remains therefore a formidable task to research for the corresponding variable so that the single-time measurement of its linear response becomes related to the PSD in Eq. (30). This at best seems possible for thermal equilibrium PSD in which an imposed energy perturbation couples to the thermal affinity $\Delta T/T$. Seemingly this is not possible, however, for the equilibrium heat flow fluctuations at absolute $T = 0$ with an inherent divergent affinity [42]. In presence of quantum coherence destroying phenomena such as high temperatures or disorder the nature of quantum correlations become suppressed. Then, the classical scenario can be used again to verify the theoretical predictions [3, 57].

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